

Over-voltage Protection Thyristor

Description

DO-214AA P Series solid state protection thyristor protect telecommunications equipment such as modems, line cards, fax machines, and other CPE.

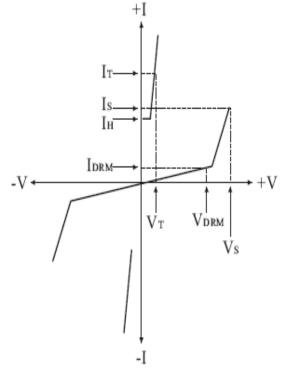
P Series devices are used to enable equipment to meet various regulatory requirements including GR 1089, ITU K.20, K.21 and K.45, IEC 60950, UL 60950, and TIA-968 (formerly known as FCC Part 68).

Compared to surge suppression using other technologies, P Series devices offer absolute surge protection regardless of the surge current available and the rate of applied voltage (dv/dt). P Series devices:

- Cannot be damaged by voltage
- Eliminate hysteresis and heat dissipation typically found with clamping devices
- Eliminate voltage overshoot caused by fast-rising transients
- Are non-degenerative
- Will not fatigu
- · Have low capacitance, making them ideal for high-speed transmission equipment

Electrical Parameters

arameter	Definition
C 0	Off-state Capacitance — typical capacitance
	measured in off state
di/dt	Rate of Rise of Current — maximum rated value of
	the acceptable rate of rise in current over time
Is	Switching Current — maximum current required to
	switch to on state
I DRM	Leakage Current — maximum peak off-state current
	measured at VDRM
IH	Holding Current — minimum current required to
	maintain on state
I PP	Peak Pulse Current — maximum rated peak impulse
	current
\mathbf{I}^{T}	On-state Current — maximum rated continuous
	on-state current
I TSM	Peak One-cycle Surge Current — maximum rated
	one-cycle AC current
V s	Switching Voltage — maximum voltage prior to
	switching to on state
VDRM	Peak Off-state Voltage — maximum voltage that can
	be applied while maintaining off state
VF	On-state Forward Voltage — maximum forward
	voltage measured at rated on-state current
VT	On-state Voltage — maximum voltage measured at
	rated on-state current





SP1500SA

P Series

ROHS

Senchip

P Series

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ctricalCha	racterist	ics							
Part	Vdrm	Vs	VT	Idrm	Is	Іт	Ін	Co	
Number*	Volts	Volts	Volts	μ Amps	mAmps	Amps	mAmps	pF	
SP1500SA	140	180	4	5	800	2.2	150	40	

* For surge ratings, see table below.

Notes:

• All measurements are made at an ambient temperature of 25°C. IPP applies to -40°C through +85°C temperature range.

• Off-state capacitance (Co) is measured at 1 MHz with a 2 V bias and is typical value.

Surge Rat:	ings						
Series	Ipp 2/10 μs Amps	Ipp 8/20 μs Amps	Ipp 10/160 μs Amps	IPP 10/560 µs Amps	IPP 10/1000 µs Amps	Ітым 60 Hz Amps	di/dt Amps∕µs
А	150	150	90	50	45	20	500
Thermal Co	onsiderations						
Package	DO-214AA/SMB	Symbol	Parameter			Value	Unit
		TJ	Operating Junction Temperature			-40 to +150	°C
		Ts	Storage Temperature Range			-40 to +150	$^{\circ}\mathrm{C}$
		R o JA	unction to	Ambient on p	120	°C/W	



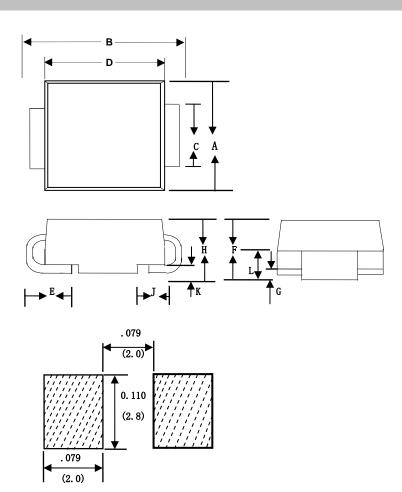
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Dimensions



SMB

Dimension	In	ches	Millimeters		
Dimension	MIN MAX		MIN	MAX	
A	0.134	0. 155	3. 40	3.94	
В	0. 205	0.22	5. 21	5.59	
С	0.075	0. 083	1.90	2.11	
D	0. 166	0. 185	4. 22	4. 70	
E	0. 036	0.056	0. 91	1.42	
F	0.073	0. 087	1.85	2.2	
G	0.002	0.008	0. 05	0. 20	
Н	0.077	0.094	1.95	2.40	
J	0. 043	0. 053	1.09	1.35	
K	0.008	0.014	0. 20	0. 35	
L	0. 039	0. 049	0. 99	1.24	



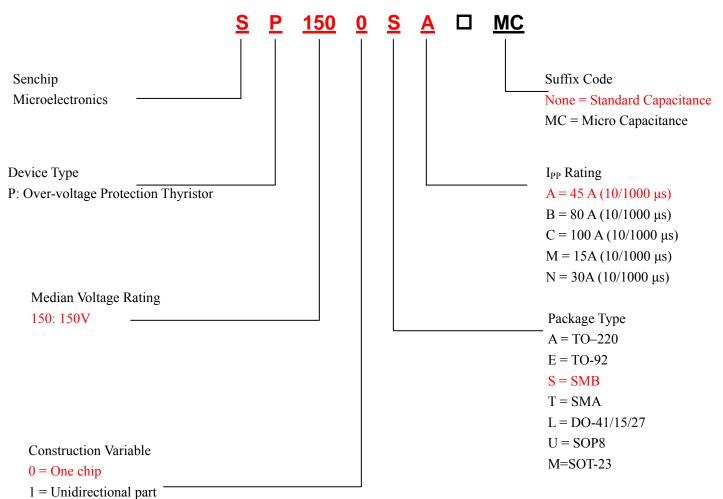
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Description of Part Number



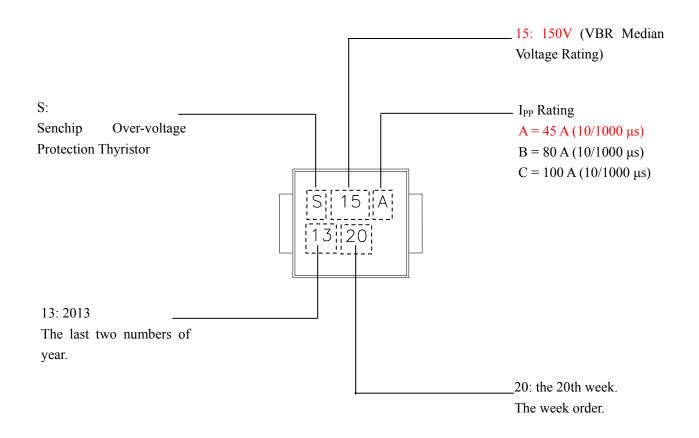
- 2 = Two chips
- 3 = Three chips



ROHS

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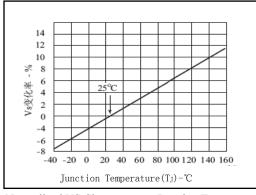
Description of Marking





Senchip	P Series						
Over-voltage Protec	tion Thyristor	SP1500SA	ROHS				
Summary of Packing Options							
Package Type	Description	Packing Quantity	Industry Standard				
DO-214AA SMB							
	Embossed Carrier Reel Pack	2500 PCS	EIA RS-481				

Thermal Derating Curves



Normalized VS Change versus Junction Temperature

